VS-MBRB20...CTPbF, VS-MBR20...CT-1PbF Series

Vishay Semiconductors

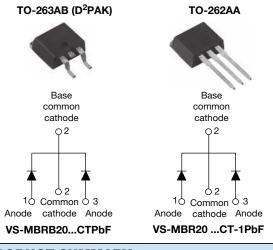
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# High Performance Schottky Rectifier, 2 x 10 A



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PRODUCT SUMMARY					
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA				
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>R</sub>	80 V, 90 V, 100 V				
V <sub>F</sub> at I <sub>F</sub>	0.70 V				
I <sub>RM</sub> max.	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	8.0 mJ				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation
- Center tap D<sup>2</sup>PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	^					
I <sub>FRM</sub>	T <sub>C</sub> = 133 °C (per leg)	20	A					
V <sub>RRM</sub>		80 to 100	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.70	V					
TJ	Range	-65 to +150	°C					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRB2080CTPbF VS-MBR2080CT-1PbF	VS-MBRB2090CTPbF VS-MBR2090CT-1PbF	VS-MBRB20100CTPbF VS-MBR20100CT-1PbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	80	90	100	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	90	100	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	Т	EST CONDITIONS	VALUES	UNITS		
Maximum average per leg	Maximum average per leg		1 V_	10			
forward current per device	I <sub>F(AV)</sub>	T <sub>C</sub> = 133 °C, rated	J VR	20			
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 133 °C		20			
Non-repetitive peak surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated $V_{\mbox{\scriptsize RRM}}$ applied	850	A		
Non-repetitive peak surge current	IFSM	Surge applied at r single phase, 60 H	ated load conditions half wave, Iz	150			
Peak repetitive reverse surge current	I <sub>RRM</sub>	2.0 μs, 1.0 kHz		0.5			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_{J} = 25 \ ^{\circ}C, \ I_{AS} = 2$	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 12 mH		mJ		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		10 A	T <sub>.1</sub> = 25 °C	0.80	- V		
Maximum forward voltage drop	V <sub>EM</sub> <sup>(1)</sup>	20 A	1j = 23 0	0.95			
Maximum forward voltage drop	V FM \	10 A	T, = 125 °C	0.70			
		20 A		0.85			
Maximum instantaneous	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.10	mA		
reverse current	'RM \''	T <sub>J</sub> = 125 °C	Haled DC vollage	6			
Threshold voltage	V <sub>F(TO)</sub>			0.433	V		
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_J = T_J maximum$		mΩ		
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal ran	400	pF			
Typical series inductance	L <sub>S</sub>	Measured from top of ter	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs			

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

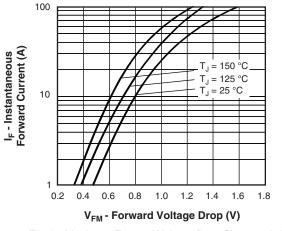
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBO	L TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature	range T <sub>J</sub>		-65 to +150	°C		
Maximum storage temperature	range T <sub>Stg</sub>		-65 to +175	C		
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	2.0			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	50			
Approvimate weight			2	g		
Approximate weight			0.07	oz.		
	nimum	Nex lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque ma	iximum	- Non-lubricated threads 12 (10)		(lbf ⋅ in)		
Marking davias		Case style D <sup>2</sup> PAK	MBRB2	0100CT		
Marking device		Case style TO-262	MBR201	100CT-1		

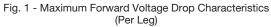
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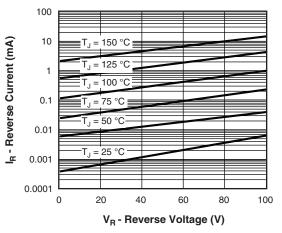


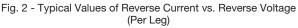
## VS-MBRB20...CTPbF, VS-MBR20...CT-1PbF Series

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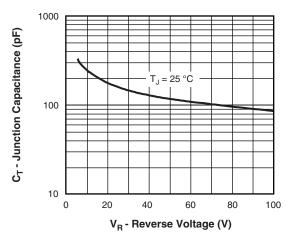


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

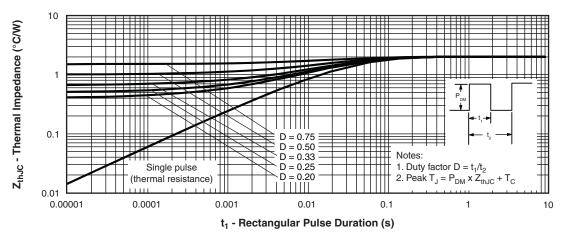
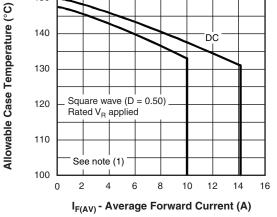


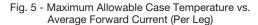
Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

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Average Power Loss (W)





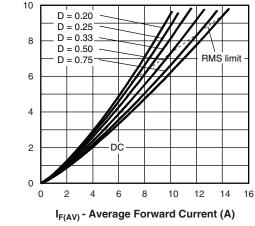


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

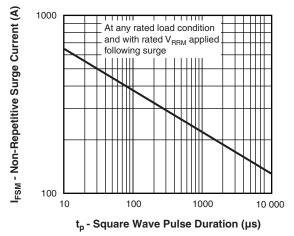


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

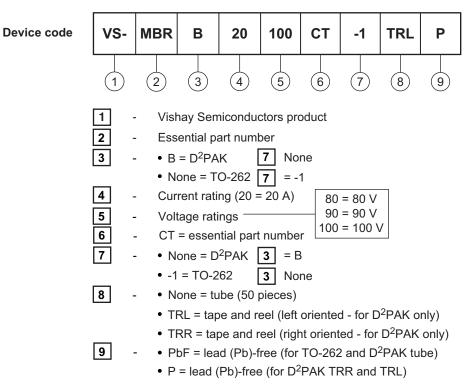
#### Note

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### VS-MBRB20...CTPbF, VS-MBR20...CT-1PbF Series

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### **ORDERING INFORMATION TABLE**

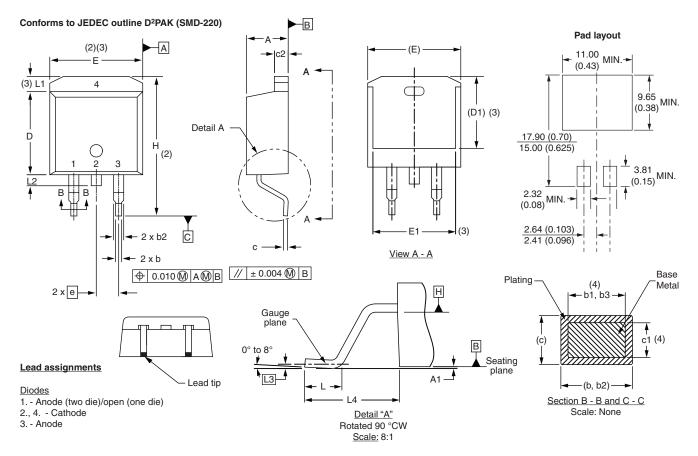


LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95014				
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			

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## D<sup>2</sup>PAK, TO-262



### DIMENSIONS - D<sup>2</sup>PAK in millimeters and inches

SHA

SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

(7) Outline conforms to JEDEC outline TO-263AB

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$ 

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

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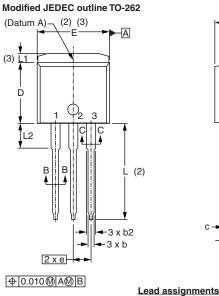
# **Outline Dimensions**

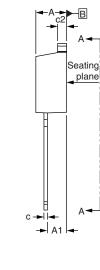
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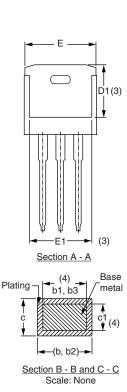
D<sup>2</sup>PAK, TO-262



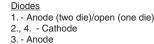
### **DIMENSIONS - TO-262** in millimeters and inches

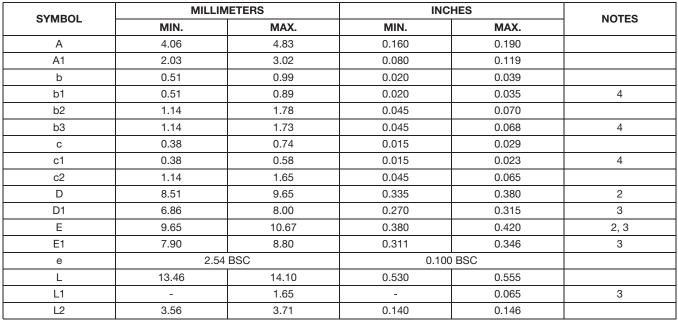






Lead tip





#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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